

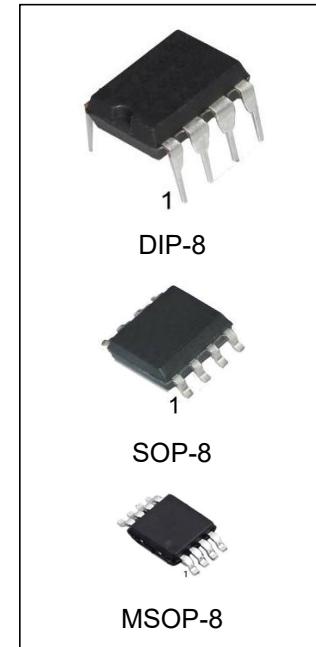
DUAL OPERATIONAL AMPLIFIER

GENERAL DESCRIPTION

The RC4560 integrated circuit is a high-gain, wide bandwidth, dual operational amplifier capable of driving 20V peak-to-peak into 400 loads. The RC4560 combines many of the features of the HG4558 as well as providing the capability of wider bandwidth, and higher slew rate make the RC4560 ideal for active filters, data and telecommunications, and many instrumentation applications.

FEATURES

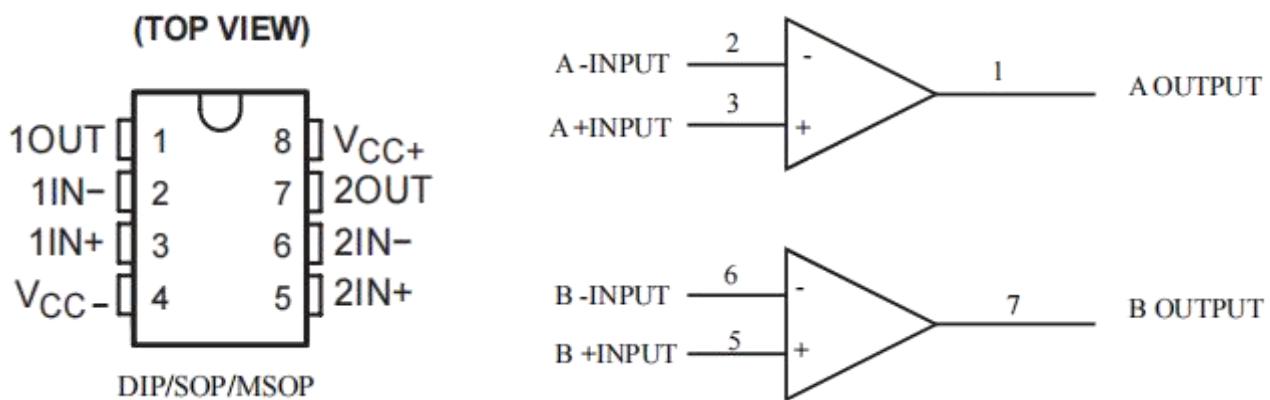
- Operating Voltage: ($\pm 4 \text{ V} \sim \pm 18 \text{ V}$)
- Wide Gain Bandwidth Product: (10 MHz typ.)
- Slew Rate: (4 V/s typ.)
- Bipolar Technology

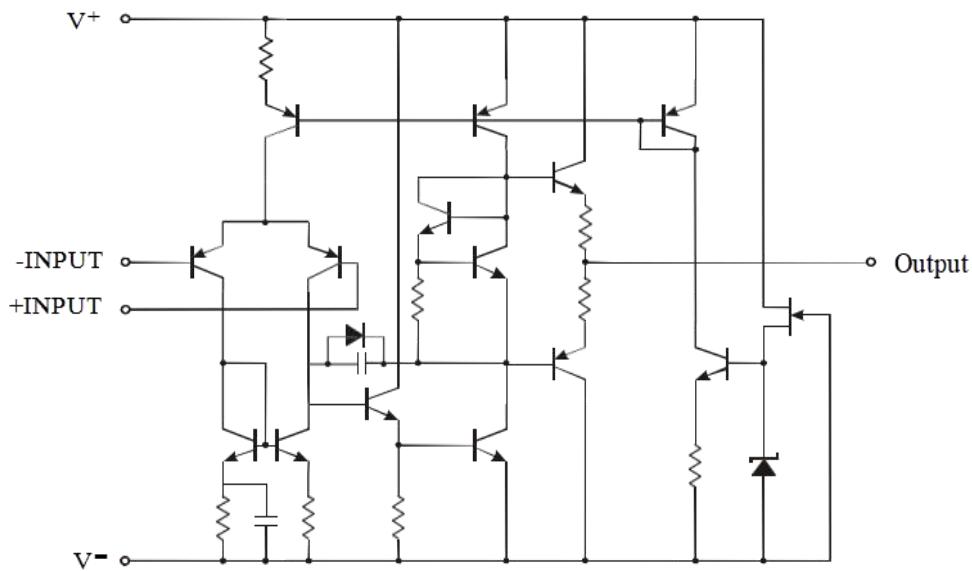


ORDERING INFORMATION

DEVICE	Package Type	MARKING	Packing	Packing Qty
RC4560N	DIP-8	RC4560,4560	TUBE	2000pcs/box
RC4560M/TR	SOP-8	RC4560,4560	REEL	2500pcs/reel
RC4560MM/TR	MSOP-8	RC4560,4560	REEL	3000pcs/reel

BLOCK DIAGRAM



EQUIVALENT CIRCUIT (1/2 Show)

ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

Symbol	Parameter	Ratings	Unit
V ⁺ /V ⁻	Supply Voltage	18	V
V _{ID}	Differential Input Voltage	30	V
V _{IC}	Input Voltage	15*	V
T _L	Lead Temperature (Soldering, 10 seconds)	260	°C
T _{opr}	Operation Temperature Range	-25~+75	°C
T _{stg}	Storage Temperature Range	-60~+125	°C

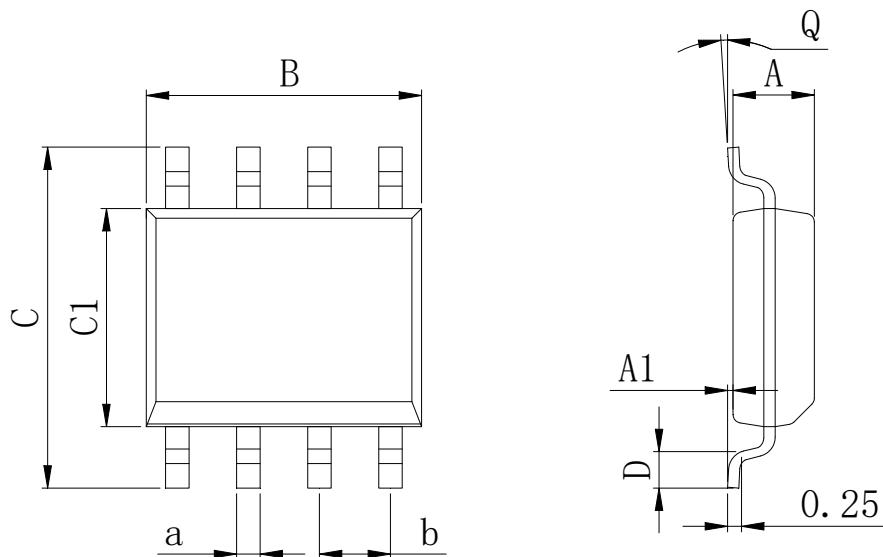
1. Note: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured.
2. *For supply voltage less than 15 V, the absolute maximum input voltage is equal to the supply voltage.

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Condition	Min	Max	Unit
V _{IO}	Input Offset Voltage	R _S ≤ 10 kΩ	-	6	mV
I _{IO}	Input Offset Current		-	200	nA
I _B	Input Bias Current		-	500	nA
R _{IN}	Input Resistance		0.3	-	MΩ
A _V	Large Signal Voltage Gain	R _L ≥ 2 kΩ, V _O = ±10 V	86	-	dB
V _{OM1}	Maximum Output Voltage Swing 1	R _L ≥ 2 kΩ	±12	-	V
V _{OM2}	Maximum Output Voltage Swing 2	I _O = 25 mA	±10	-	V
V _{ICM}	Input Common Mode Voltage Range		±12	-	V
CMR	Common Mode Rejection Ratio	R _S ≤ 10 kΩ	70	-	dB
SVR	Supply Voltage Rejection Ratio	R _S ≤ 10 kΩ	76.5	-	dB
I _{CC}	Operating Current		-	5.7	mA
SR	Slew Rate	R _L ≥ 2 kΩ	3	5	V/μs

Physical Dimensions

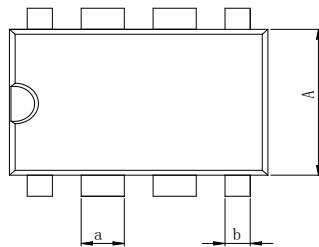
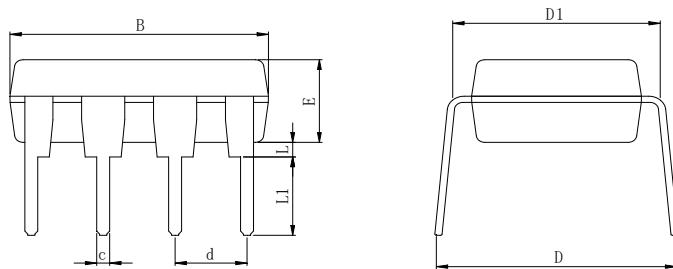
SOP-8



Dimensions In Millimeters(SOP-8)

Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1.27 BSC
Max:	1.55	0.20	5.10	6.20	4.00	0.80	8°	0.45	

DIP-8

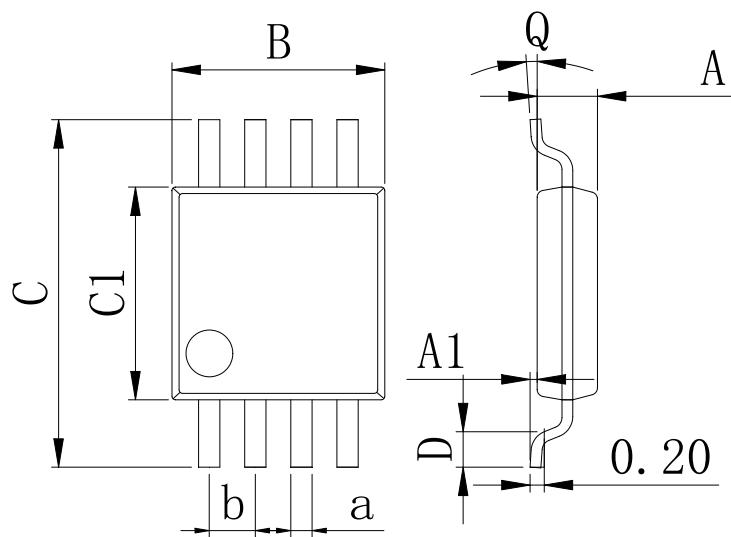


Dimensions In Millimeters(DIP-8)

Symbol:	A	B	D	D1	E	L	L1	a	b	c	d
Min:	6.10	9.00	8.10	7.42	3.10	0.50	3.00	1.50	0.85	0.40	2.54 BSC
Max:	6.68	9.50	10.9	7.82	3.55	0.70	3.60	1.55	0.90	0.50	

PHYSICAL DIMENSIONS

MSOP-8



Dimensions In Millimeters(MSOP-8)									
Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	0.80	0.05	2.90	4.75	2.90	0.35	0°	0.25	0.65 BSC
Max:	0.90	0.20	3.10	5.05	3.10	0.75	8°	0.35	

Revision History

DATE	REVISION	PAGE
2018-3-15	New	1-6
2023-9-14	Update encapsulation type、Updated DIP-8 dimension	1、3
2024-11-5	Add a model marking name、Update Lead Temperature	1、2

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